

Ultrafast Rectifier

HFA32PA120C

FEATURES

- Guarding for over voltage protection
- Dual rectifier construction, positive center tap
- Metal of silicon rectifier, majority carrier conduction
- · Low forward voltage, high efficiency
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

PIN:1 Anode 2 Cathode 3 Anode 1 2 3 TO-247 package

APPLICATIONS

- Switching power supply
- · Rectifier in switch mode supplies



SYMBOL	PARAMETER	VALUE	UNIT
V _{RRM} V _{RWM} V _R	Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	1200	V
I _{F(AV)}	Average Rectified Forward Current	32	Α
IFSM	Nonrepetitive Peak Surge Current (Surge applied at rated load conditions half-wave, single phase, 60Hz)	190	Α
P _D	Maximum power dissipation	151	W
TJ	Junction Temperature	-55~150	$^{\circ}$ C
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$ C

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	DIM	m	m	
	DIM A	000710		
	Α	m MIN	m MAX	
		MIN 19.80 15.40 4.90	MAX 20.20 15.80 5.10	
	A B C D	MIN 19.80 15.40 4.90 0.90	MAX 20.20 15.80 5.10 1.10	
	A B C D	MIN 19.80 15.40 4.90 0.90	MAX 20.20 15.80 5.10 1.10	
	A B C D E	MIN 19.80 15.40 4.90 0.90 1.40 1.90	MAX 20.20 15.80 5.10 1.10 1.60 2.10	
	A B C D E F	MIN 19.80 15.40 4.90 0.90 1.40 1.90	MAX 20.20 15.80 5.10 1.10 1.60 2.10	
	A B C D E F G	m 19.80 15.40 4.90 0.90 1.40 1.90 10.80 2.40	MAX 20.20 15.80 5.10 1.10 1.60 2.10 11.00 2.60	
	A B C D F G H J	m 19.80 15.40 4.90 0.90 1.40 1.90 10.80 2.40 0.50	MAX 20.20 15.80 5.10 1.10 1.60 2.10 11.00 2.60	
	A B C D E F G H J	m MIN 19.80 15.40 4.90 0.90 1.40 1.90 10.80 2.40 0.50 19.50	MAX 20.20 15.80 5.10 1.10 1.60 2.10 11.00 2.60 0.70 20.50	
	A B C D E F G H J K	MIN 19.80 15.40 4.90 0.90 1.40 1.90 10.80 2.40 0.50 19.50 3.90	MAX 20.20 15.80 5.10 1.10 1.60 2.10 11.00 2.60 0.70 20.50 4.10	
	A B C D E F G H J K P Q	m MIN 19.80 15.40 4.90 0.90 1.40 1.90 10.80 2.40 0.50 19.50 3.90 3.30	MAX 20.20 15.80 5.10 1.10 1.60 2.10 11.00 2.60 0.70 20.50 4.10 3.50	
	A B C D E F G H J K	MIN 19.80 15.40 4.90 0.90 1.40 1.90 10.80 2.40 0.50 19.50 3.90	MAX 20.20 15.80 5.10 1.10 1.60 2.10 11.00 2.60 0.70 20.50 4.10	

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance,Junction to Case	0.83	°C/W

ELECTRICAL CHARACTERISTICS(Ta=25℃) (Pulse Test: Pulse Width=300 µ s,Duty Cycle≤2%)

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
V _F	Maximum Instantaneous Forward Voltage	I_F = 16A ; T_j =25 °C I_F = 16A ; T_j =125 °C	3.0 2.7	V
I _R	Maximum Instantaneous Reverse Current	$V_{R} = V_{RRM}; T_{j} = 25 ^{\circ}C$ $V_{R} = 0.8 V_{RRM}; T_{j} = 125 ^{\circ}C$	20 2	μA mA
t _{rr}	Maximum Reverse Recovery Time	I _F =1A;dI _F /dt = 200 A/μs, V _R = 30 V	60	ns



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